ABSOLUTE MAXIMUM RATINGS

IN to GND
FB to GND0.3V to the lower of 5.5V and $(V_{IN} + 0.3V)$
PGND to GND0.3V to +0.3V
Continuous Power Dissipation (T _A =+70°C)
5-Pin SC70 (derate 3.1mW/°C above +70°C)246.9mW 5-Pin Thin SOT23 (derate 9.1mW/°C above +70°C)727mW

Operating Temperature Range	40°C to +85°C
Junction Temperature Range	40°C to +150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

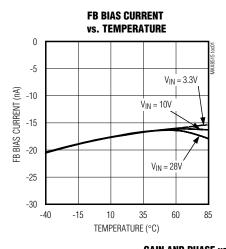
(V_{IN} = 3.3V, OUT = FB, I_{OUT} = 5mA, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

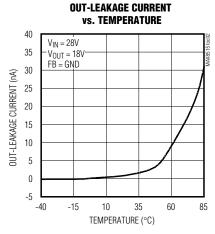
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
IN							
IN Voltage Range	V _{IN}			1.7		28	V
IN Supply Current	lu.	V 0V/+- 00V/	$I_{OUT} = 0.3mA$		0.5	1	^
	I _{IN}	$V_{IN} = 2V \text{ to } 28V$	I _{OUT} = 10mA		2.5	4	mA
FB							
		T _A = +25°C	MAX8515AE_K	0.597	0.6	0.603	
		TA = +25 C	MAX8515E_K	0.594	0.6	0.606	
FB Threshold Accuracy		T _A = 0°C to +85°C	MAX8515AE_K	0.595	0.6	0.605	V
FB Threshold Accuracy		TA = 0 C t0 +65 C	MAX8515E_K	0.592	0.6	0.608	V
		T 4000 L 0500	MAX8515AE_K	0.594	0.6	0.606	-
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	MAX8515E_K	0.589	0.6	0.608	
FB Load Regulation		I _{OUT} = 1mA to 20mA			3.8	6	mV
FB Line Regulation		$V_{IN} = 2V$ to $28V$			0.2	1	m)/
		V _{IN} = 1.7V to 28V				1.5	mV
FB Output Voltage Regulation		$V_{OUT} = 0.2V$ to 18V, $I_{OUT} = 1$ mA			0.2	1	mV
FB Input Bias Current	IFB(BIAS)	$V_{IN} = 28V$		-0.1	0.02	+0.1	μΑ
OUT							
OUT Voltage Range	Vout			0.2		18	V
Maximum Output Current	IOUT(MAX)	V _{OUT} = 0.2V, V _{IN} = 2V, V _{FB} = 0.63V		20			mA
Output Leakage Current	1	V _{IN} = 28V, V _{OUT} = 18V,	T _A = +25°C		0.001	0.1	
	IOUT(LEAK)	V _{FB} = 0V	T _A = +85°C		0.03		μΑ
Dynamic Output Impedance	Z _{OUT}	I _{OUT} = 1mA to 20mA, f <1kHz			0.2	0.32	Ω

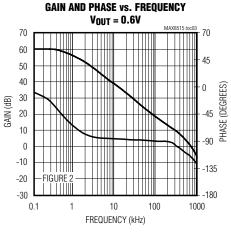
Note 1: Devices are production tested at $T_A = +25$ °C, limits over temperature are guaranteed by design.

Typical Operating Characteristics

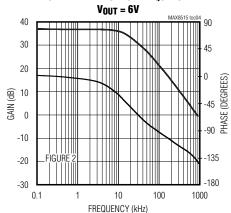
 $(V_{IN} = 3.3V, I_{OUT} = 5mA, FB = OUT, circuit in Figure 1, C1 = 0.1 \mu F, C2 = 1 \mu F, T_A = +25 ^{\circ}C, unless otherwise specified.)$



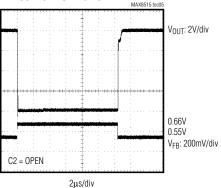




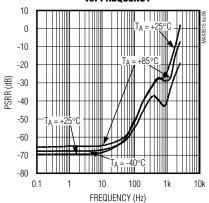
GAIN AND PHASE vs. FREQUENCY



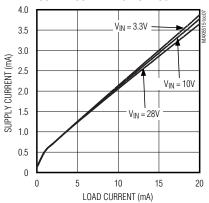




POWER-SUPPLY REJECTION RATIO vs. FREQUENCY



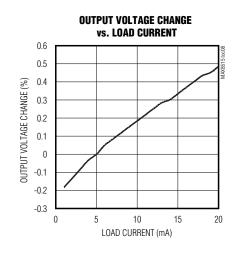
SUPPLY CURRENT vs. LOAD CURRENT

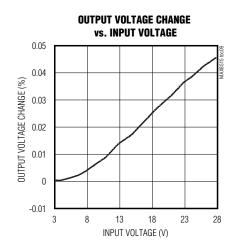




Typical Operating Characteristics (continued)

 $(V_{IN} = 3.3V, I_{OUT} = 5mA, FB = OUT, circuit in Figure 1, C1 = 0.1\mu F, C2 = 1\mu F, T_A = +25^{\circ}C, unless otherwise specified.)$





Pin Description

PIN	NAME	FUNCTION		
1	PGND	Power Ground. Connect PGND and GND together.		
2	GND	Analog Ground. Connect GND and PGND together.		
3	OUT	Output. Connect a ceramic capacitor from OUT to GND. See the Applications Information section.		
4	IN	Supply Input. Connect a 0.1µF capacitor to GND.		
5	FB	Feedback Input. Regulates to 600mV.		

Detailed Description

The MAX8515A/MAX8515 adjustable shunt regulators feature isolated supply inputs and outputs, ideal for isolated power-supply applications using an optocoupler in the feedback path. The MAX8515A/MAX8515 sink 20mA with Vout at 0.2V. The wide input supply range allows the device to operate from 1.7V to 28V. The MAX8515A/MAX8515 compare the FB input to a precision 600mV reference. If the FB input is low, OUT sinks no current. If FB rises above 600mV, OUT sinks up to 20mA.

_Applications Information

Shunt Regulator/Adjustable Voltage Reference

Figure 1 shows the MAX8515A/MAX8515 configured as a shunt regulator. Connect FB to OUT for an output voltage of 0.6V. Connect a 1.0µF capacitor from OUT to GND

when the output voltage is 0.6V. A resistor-divider connected from OUT to GND produces higher output voltages and allows for a smaller output capacitor. The value of the output capacitor is inversely proportional to the output voltage:

$$V_{OUT} = 0.6 \times \left(1 + \frac{R1}{R2}\right)$$

$$C_{OUT} = 1\mu F \times \left(\frac{0.6}{V_{OUT}}\right)$$

Set the current limit with a resistor connected from IN to OUT. This type of shunt regulator is limited to low-current applications. The MAX8515A/MAX8515 can typically sink up to 20mA in this application.

Figure 2 shows the test circuits for gain and phase plots.

MIXIM

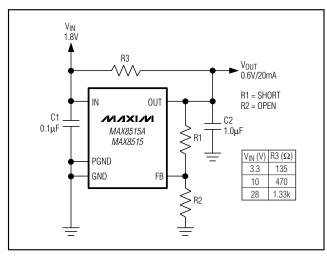


Figure 1. MAX8515A/MAX8515 Typical Application Circuit, Shunt Regulator/Adjustable Voltage Reference

Optical Feedback Setting Vout

Figure 3 displays an application circuit using the MAX8515A/MAX8515 in an opto-isolated feedback circuit. The maximum bias current for the photodiode is set with R1. The isolated DC-to-DC converter compensation circuit is formed with R2, C3, and C4. Resistors R3 and R4 set the isolated DC-to-DC converter output voltage. C1 decouples the input supply and C2 is needed to stabilize the MAX8515A/MAX8515. Calculate VBEG with the following equation:

$$V_{REG} = 0.6 \times \left(1 + \frac{R3}{R4}\right)$$

Set R4 to $10k\Omega$ and calculate R3 by:

$$R3 = \left(\frac{V_{OUT}}{V_{FB}} - 1\right) \times R4$$

For example, given a regulator output voltage of 1.8V and R4 = $10k\Omega$, R3 is found to be $20k\Omega$.

Compensation Circuit

A typical compensation scheme is depicted in Figure 3. C3 provides an integrator function that minimizes output regulation error.

R2 provides additional phase compensation at the zero frequency f_z :

$$f_Z = \frac{1}{2\pi \times R2 \times C3}$$

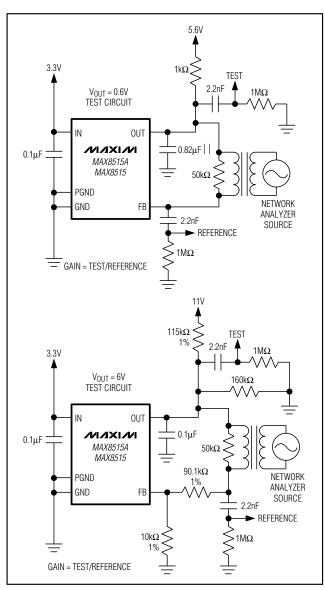


Figure 2. Test Circuits for Gain and Phase Plots

The midband gain is given by:

$$A = \frac{R2}{R3}$$

Add C4 for high-frequency noise rejection. Determine R2 based on the midband gain required by the isolated power supply. Choose f_Z based on the power supply small-signal transfer function. Calculate C3 once f_Z is known.

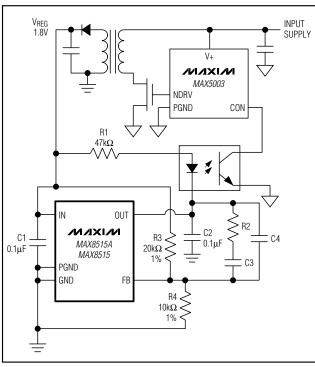


Figure 3. MAX8515A/MAX8515 Typical Application Circuit, Opto-Feedback Circuit

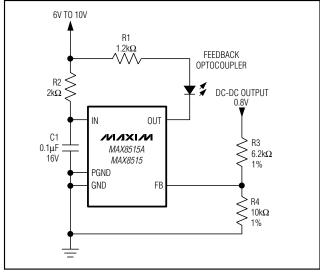


Figure 4. MAX8515A/MAX8515 Typical Application Circuit, OVP Circuit (Set to 1V OVP Threshold for 0.8V Nominal Output)

Overvoltage Protection

Figure 4 shows an isolated OVP circuit. R1 limits the current supplied to the photodiode. R2 limits the MAX8515A/MAX8515 input current. R3 and R4 set the trip threshold for the OVP. C1 is the input supply decoupling capacitor.

Values for R3 and R4 are chosen based on the needed OVP threshold. For example, a trip threshold of 25% above the rated output voltage is needed for an OVP circuit. The values of R3 can be determined from the following equation once R4 is chosen; $10k\Omega$ is recommended for R4. Then, R3 = $6.2k\Omega$.

$$R3 = \left(\frac{V_{OVP}}{V_{FB}} - 1\right) \times R4$$

where $V_{OVP} = 0.8V \times 1.25$ for the given example.

Linear Regulator

Use an external pass transistor in conjunction with the MAX8515A/MAX8515 to create a linear regulator as shown in Figure 5. Determine the output voltage of the regulator by:

$$V_{REG} = 0.6V \times \left(1 + \frac{R2}{R3}\right)$$

Choose R1 to maintain load regulation up to a 2A load. Use the following equation:

$$R1 = \frac{V_{IN_MIN} - V_{REG} - V_{BE}}{I_{O_MAX}} \times \beta$$

where IO_MAX is the rated maximum output current, which is 2A in this application circuit. VREG is the output voltage of the linear regulator. VBE is the base-to-emitter forward voltage of Q1, and β is the minimum current gain of Q1 at rated load current. VIN is the minimum input voltage at IN. For the typical application circuit, VIN_MIN = 2.375V, VREG = 1.0V, VBE = 0.65V, and β = 180. Choose R1 = 15 Ω for fast transient response. C1 is the input decoupling capacitor and C2 is the compensation capacitor. Use a 1 μ F, 6.3V capacitor for this application. Figure 6 shows a typical load-regulation curve for the circuit in Figure 5. This circuit does not provide short-circuit, overcurrent, or overtemperature protection.

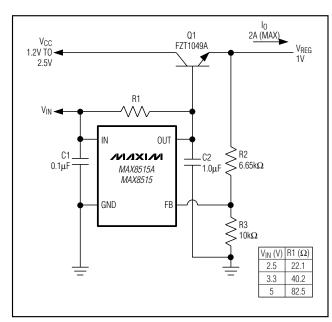


Figure 5. MAX8515A/MAX8515 Typical Application Circuit, Linear Regulator

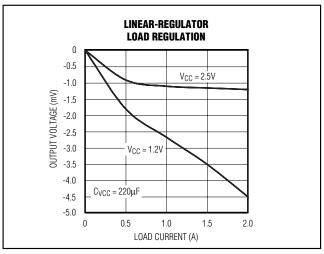
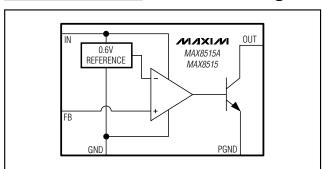


Figure 6. Load Regulation of Linear-Regulator Circuit

Functional Diagram



Selector Guide

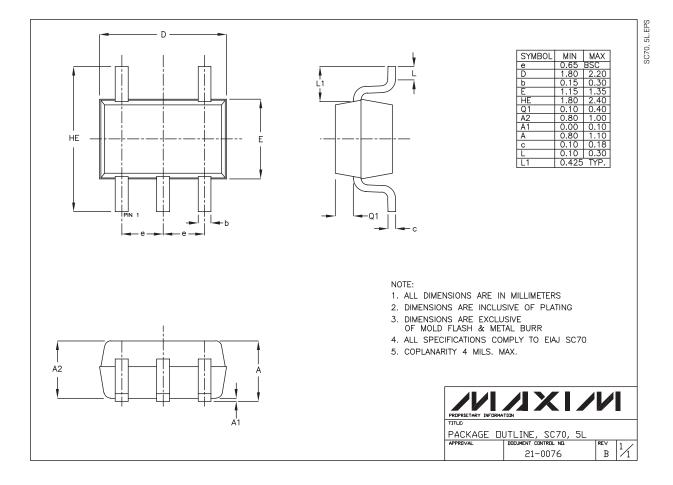
PART INITIAL ACCURACY		TOP MARKS
MAX8515AEXK-T	0.6V, 0.5% feedback	ADX
MAX8515AEZK-T	0.6V, 0.5% feedback	ADRK
MAX8515EXK-T	0.6V, 1% feedback	ADY
MAX8515EZK-T	0.6V, 1% feedback	ADRL

Chip Information

TRANSISTOR COUNT: 50 PROCESS: BICMOS

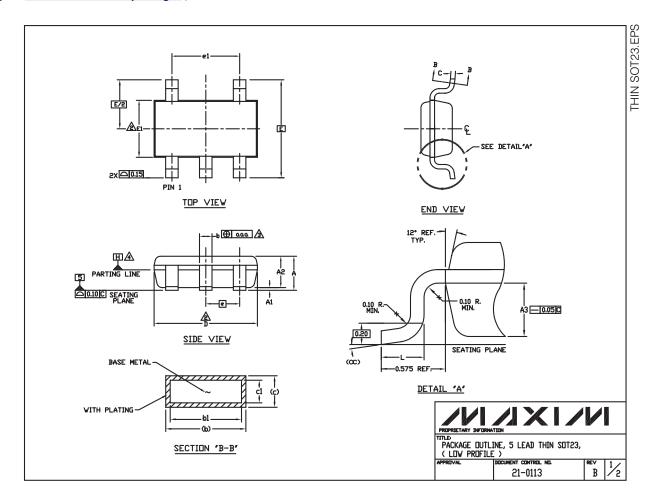
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.

"D" AND "E1" ARE REFERENCE DATUM AND DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS, AND ARE MEASURED AT THE BOTTOM PARTING LINE. MOLD FLASH OR PROTRUSION SHALL NOT EXCEED 0.15mm ON "D" AND 0.25mm ON "E" PER SIDE.

THE LEAD WIDTH DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.07mm TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION.

DATUM PLANE "H" LOCATED AT MOLD PARTING LINE AND COINCIDENT WITH LEAD, WHERE LEAD EXITS PLASTIC BODY AT THE BOTTOM OF PARTING LINE.

THE LEAD TIPS MUST LINE WITHIN A SPECIFIED TOLERANCE ZONE. THIS TOLERANCE ZONE IS DEFINED BY TWO PARALLEL LINES. ONE PLANE IS THE SEATING PLANE, DATUM [-C-]; AND THE OTHER PLANE IS AT THE SPECIFIED DISTANCE FROM [-C-] IN THE DIRECTION INDICATED. FORMED LEADS SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITH 0.10mm AT SEATING PLANE.

6. THIS PART IS COMPLIANT WITH JEDEC SPECIFICATION
MO-193 EXCEPT FOR THE "e" DIMENSION WHICH IS 0.95Mmm
INSTEAD OF 1.00mm. THIS PART IS IN FULL COMPLIANCE TO
EIAJ SPECIFICATION SC-74.

SYMBOLS			
	MIN	NDM	MAX
Α	ı	-	1.10
A1	0.05	0.075	0.10
A2	0.85	0.88	0.90
A3	0.50 BSC		
b	0.30	-	0.45
b1	0.25	0.35	0.40
С	0.15	-	0.20
c 1	0.12	0.127	0.15
D	2.80	2.90	3.00
E	2.75 BSC		
E1	1.55	1.60	1.65
L	0.30	0.40	0.50
e1	1.90 BSC		
e	0.95 BSC		
∞	0-	4-	8-
ممم	0.20		



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